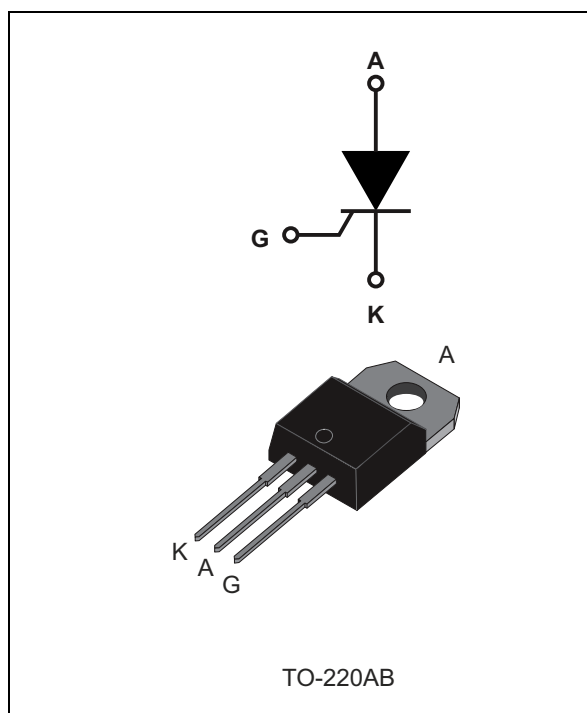


High temperature 20 A SCRs

Datasheet — production data



Description

Thanks to a junction temperature T_j up to 150 °C and a non-isolated TO-220 package, the TN2015H-6T offers high thermal performance up to 20 A rms.

The trade-off between the device's noise immunity ($dV/dt = 750 \text{ V}/\mu\text{s}$), its gate triggering current ($I_{GT} = 15 \text{ mA}$) and its turn-on current rise ($dI/dt = 100 \text{ A}/\mu\text{s}$) allows the design of robust and compact control circuits for voltage regulators in motorbikes and industrial drives, overvoltage crowbar protection, motor control circuits in power tools and kitchen appliances, and inrush current limiting circuits.

Table 1. Device summary

Order code	Package	V_{DRM}/V_{RRM}	I_{GT}
TN2015H-6T	TO-220AB	600 V	15 mA

Features

- High junction temperature: $T_j = 150 \text{ °C}$
- High noise immunity $dV/dt = 750 \text{ V}/\mu\text{s}$ up to 150 °C
- Gate triggering current $I_{GT} = 15 \text{ mA}$
- Blocking voltage $V_{DRM}/V_{RRM} = 600 \text{ V}$
- High turn on current rise $dI/dt: 100 \text{ A}/\mu\text{s}$
- ECOPACK®2 compliant component

Applications

- Voltage regulator circuits for motorbikes
- Inrush current limiting circuits
- Motor control circuits and starters
- Light dimmers
- Solid state relays

1 Characteristics

Table 2. Absolute ratings

Symbol	Parameter			Value	Unit
I _{T(RMS)}	On-state rms current (180° conduction angle)		T _c = 132 °C	20	A
I _{T(AV)}	Average on-state current (180° conduction angle)		T _c = 132 °C	12.7	A
			T _c = 137 °C	10	
			T _c = 140 °C	8	
I _{TSM}	Non repetitive surge peak on-state current (T _j initial = 25 °C)		t = 8.3 ms	197	A
			t = 10 ms	180	
I ² t	I ² t value for fusing (T _j initial = 25 °C)		t _p = 10 ms	162	A ² s
dI/dt	Critical rate of rise of on-state current I _G = 2 x I _{GT} , t _r ≤ 100 ns, T _j = 25 °C		F = 60 Hz	100	A/μs
V _{DRM} , V _{RRM}	Repetitive peak off-state voltage			600	V
I _{GM}	Peak gate current	t _p = 20 μs	T _j = 150 °C	4	A
P _{G(AV)}	Average gate power dissipation		T _j = 150 °C	1	W
T _{stg}	Storage junction temperature range			- 40 to + 150	°C
T _j	Operating junction temperature range			- 40 to + 150	
T _L	Maximum lead temperature for soldering during 10 s			260	°C

Table 3. Electrical characteristics ($T_j = 25\text{ °C}$, unless otherwise specified)

Symbol	Test conditions			Value	Unit
I_{GT}	$V_D = 12\text{ V}$, $R_L = 33\text{ }\Omega$		Typ.	6	mA
			Max.	15	
V_{GT}	$V_D = 12\text{ V}$, $R_L = 33\text{ }\Omega$		Max.	1.3	V
V_{GD}	$V_D = V_{DRM}$, $R_L = 3.3\text{ k}\Omega$	$T_j = 150\text{ °C}$	Min.	0.2	V
I_H	$I_T = 500\text{ mA}$, gate open		Max.	50	mA
I_L	$I_G = 1.2 \times I_{GT}$		Max.	60	mA
dV/dt	$V_D = 402\text{ V}$, gate open	$T_j = 150\text{ °C}$	Min.	750	V/ μ s
t_{gt}	$I_T = 40\text{ A}$, $V_D = 600\text{ V}$, $I_G = 100\text{ mA}$, (dI_G/dt)max = 0.2 A/ μ s		Typ	1.9	μ s
t_q	$V_D = 402\text{ V}$, $V_R = 25\text{ V}$, $I_T = 20\text{ A}$, (dI_G/dt)max = 30A/ μ s, $dV_D/dt = 50\text{ V}/\mu$ s	$T_j = 150\text{ °C}$	Typ	70	μ s

Table 4. Static characteristics

Symbol	Test conditions			Value	Unit
V_{TM}	$I_{TM} = 40 \text{ A}$, $t_p = 380 \mu\text{s}$	$T_j = 25 \text{ }^\circ\text{C}$	Max.	1.6	V
V_{t0}	Threshold voltage	$T_j = 150 \text{ }^\circ\text{C}$	Max.	0.82	V
R_d	Dynamic resistance	$T_j = 150 \text{ }^\circ\text{C}$	Max.	17.5	m Ω
I_{DRM} , I_{RRM}	$V_D = V_{DRM}$, $V_R = V_{RRM}$	$T_j = 25 \text{ }^\circ\text{C}$	Max.	5	μA
		$T_j = 150 \text{ }^\circ\text{C}$		2	mA

Table 5. Thermal resistance

Symbol	Parameter	Value	Unit
$R_{th(j-c)}$	Junction to case (AC)	1.0	$^\circ\text{C/W}$
$R_{th(j-a)}$	Junction to ambient (DC)	60	$^\circ\text{C/W}$

Figure 1. Maximum power dissipation versus average on-state current

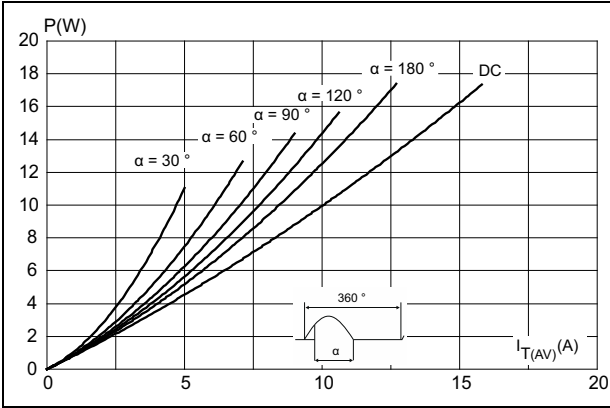


Figure 2. Average and DC on-state current versus case temperature

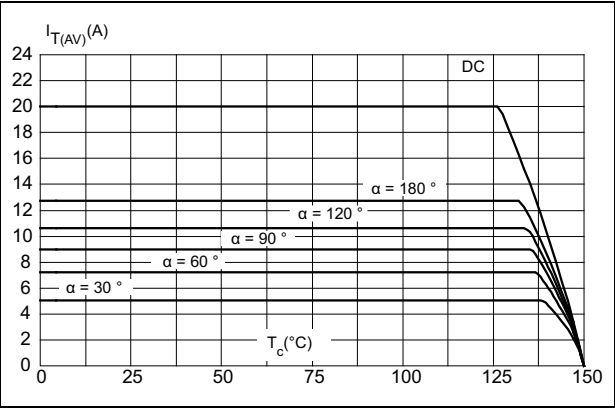


Figure 3. Average and DC on-state current versus ambient temperature

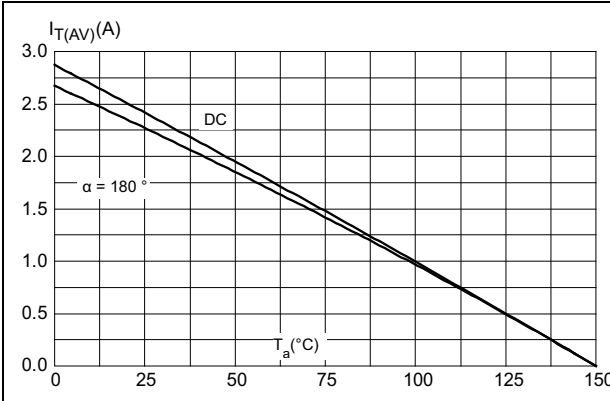


Figure 4. Relative variation of thermal impedance versus pulse duration

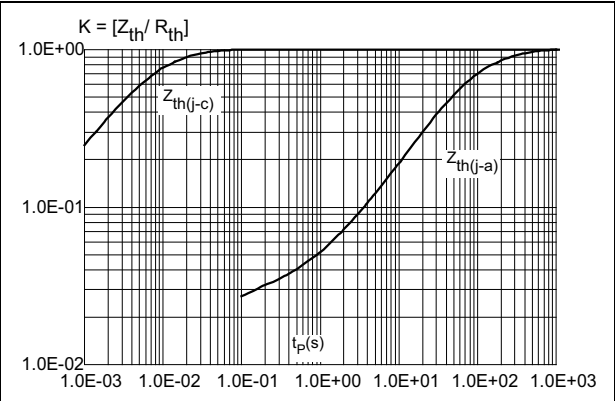


Figure 5. Relative variation of gate triggering current and gate voltage versus junction temperature (typical values)

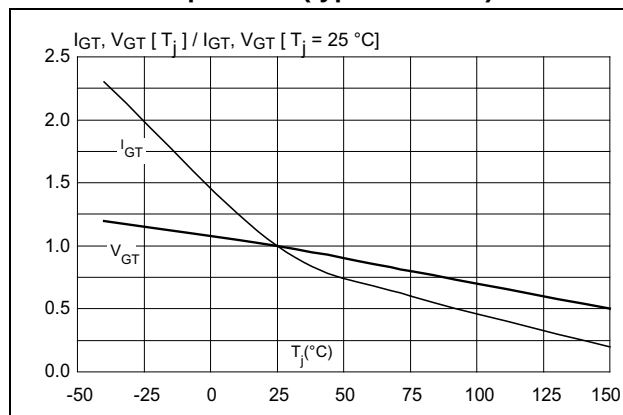


Figure 6. Relative variation of holding current and latching current versus junction temperature (typical values)

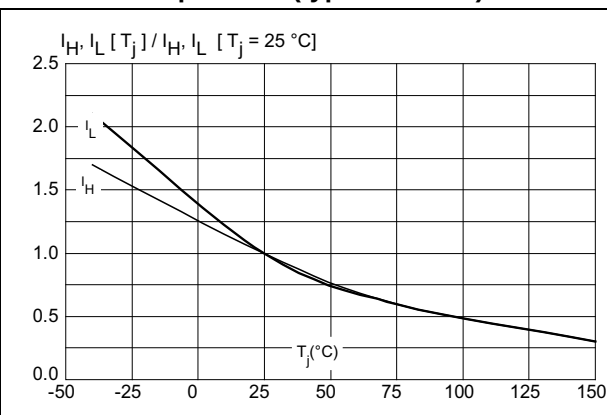


Figure 7. Relative variation of static dV/dt immunity versus junction temperature (typical values)

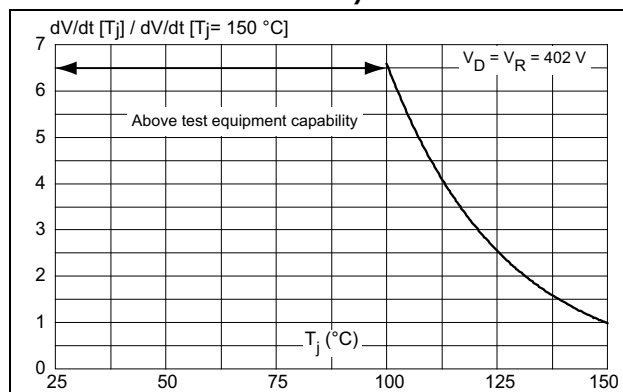


Figure 8. Surge peak on-state current versus number of cycles

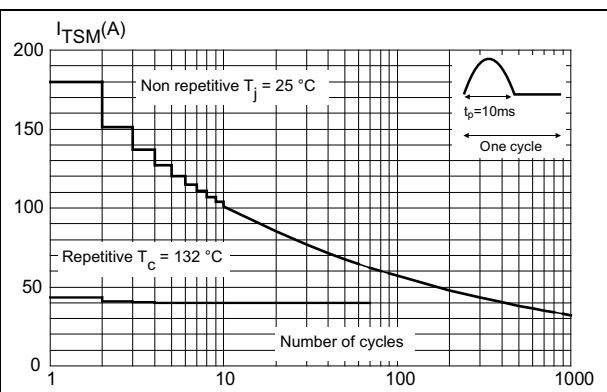


Figure 9. Non-repetitive surge peak on-state current for a sinusoidal pulse (tp < 10 ms)

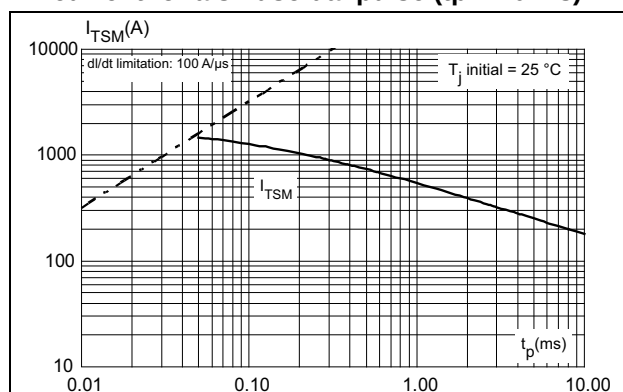


Figure 10. On-state characteristics (maximum values)

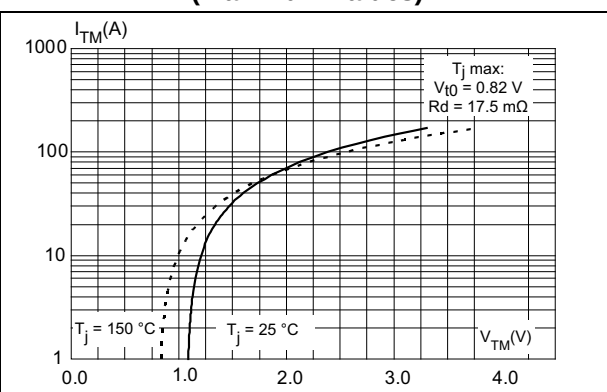
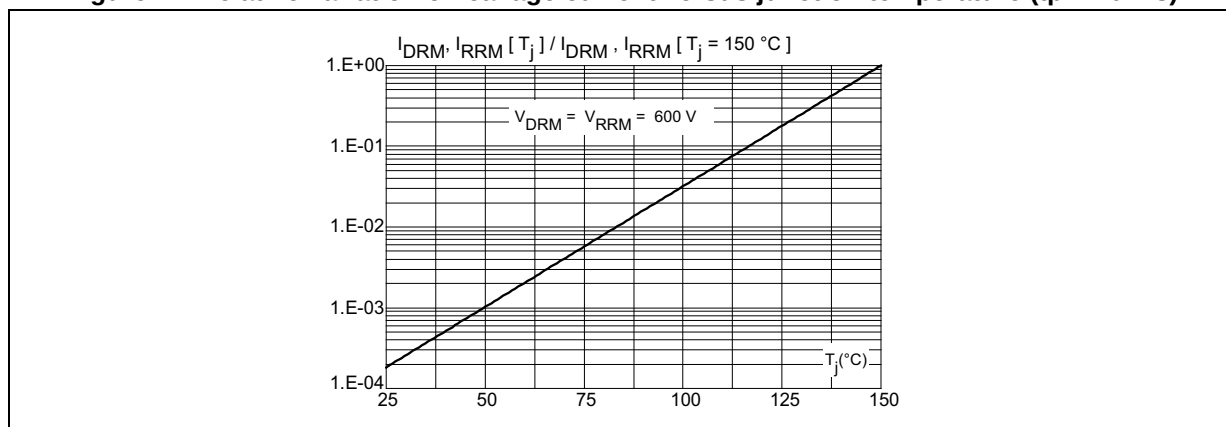


Figure 11. Relative variation of leakage current versus junction temperature ($t_p < 10$ ms)

2 Package information

- Epoxy meets UL94, V0
- Lead-free package
- Halogen free molding compound
- Recommended torque: 0.4 to 0.6 N·m

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.

Figure 12. TO-220AB dimension definitions

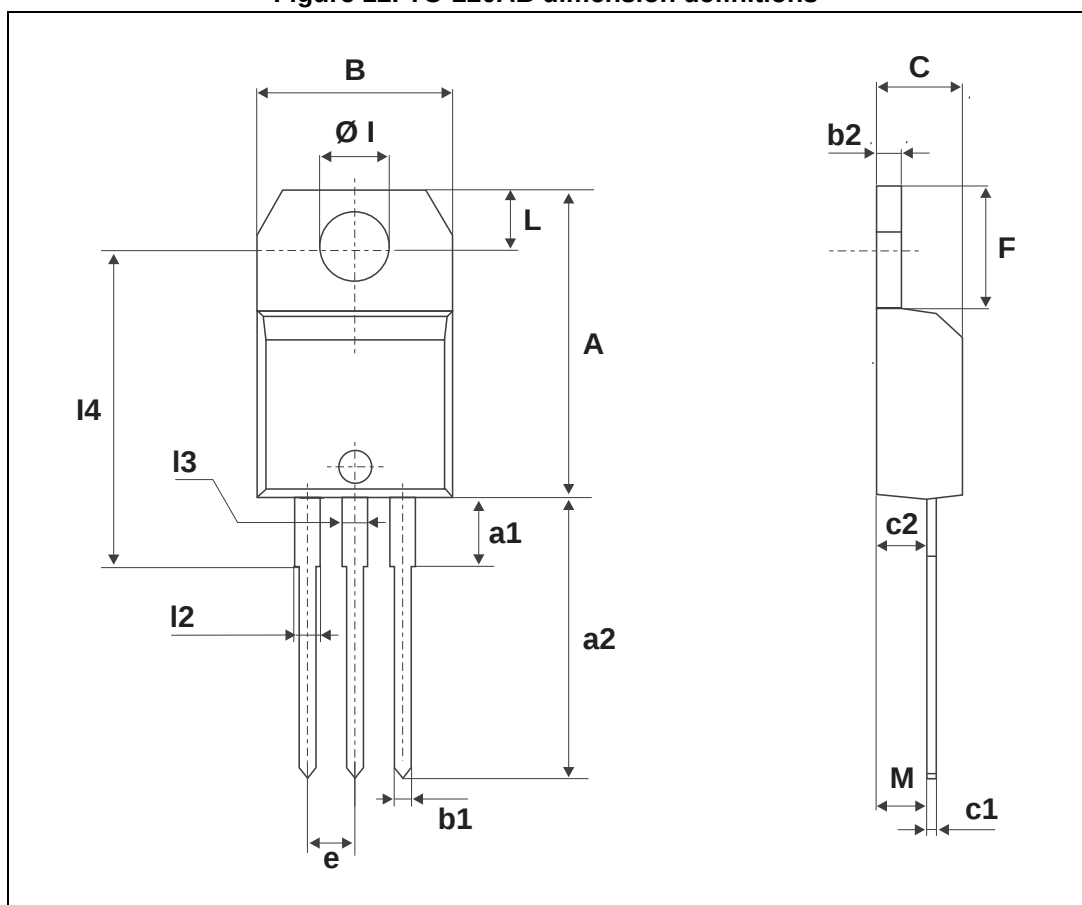


Table 6. TO-220AB dimension values

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	15.20		15.90	0.598		0.625
a1		3.75			0.147	
a2	13.00		14.00	0.511		0.551
B	10.00		10.40	0.393		0.409
b1	0.61		0.88	0.024		0.034
b2	1.23		1.32	0.048		0.051
C	4.40		4.60	0.173		0.181
c1	0.49		0.70	0.019		0.027
c2	2.40		2.72	0.094		0.107
e	2.40		2.70	0.094		0.106
F	6.20		6.60	0.244		0.259
ØI	3.75		3.85	0.147		0.151
I4	15.80	16.40	16.80	0.622	0.646	0.661
L	2.65		2.95	0.104		0.116
I2	1.14		1.70	0.044		0.066
I3	1.14		1.70	0.044		0.066
M		2.60			0.102	

3 Ordering information

Figure 13. Ordering information scheme

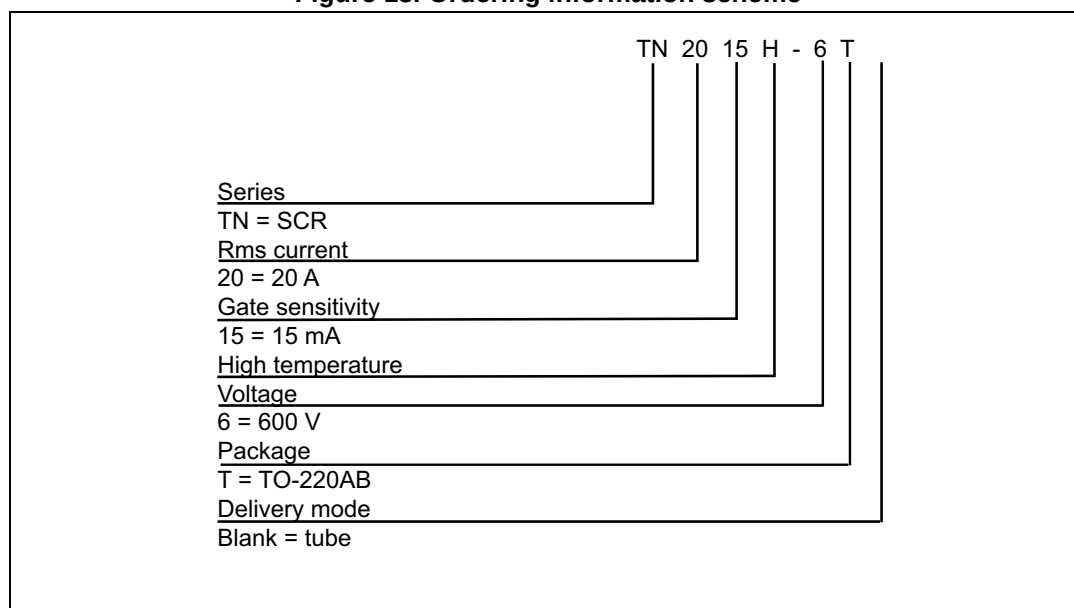


Table 7. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
TN2015H-6T	TN2015H6	TO-220AB	2.3 g	50	Tube

4 Revision history

Table 8. Document revision history

Date	Revision	Changes
25-Feb-2015	1	Initial release.

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